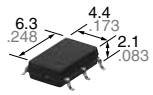
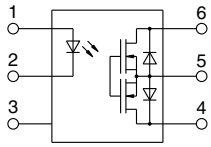
Normally closed SOP6-pin type of 400V load voltage

PhotoMOS® GU SOP 1 Form B (AQV414S)



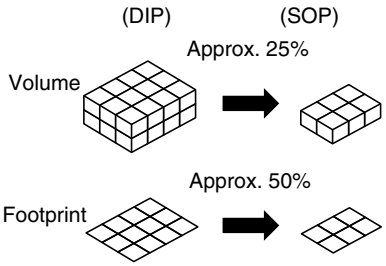
mm inch



RoHS compliant

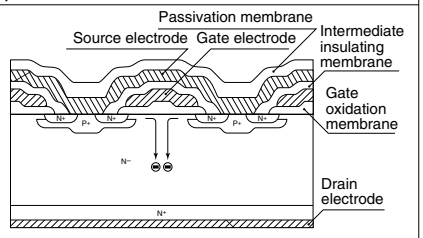
FEATURES

1. Miniature SOP6-pin package
The device comes in a small SOP measuring (W) 4.4 × (L) 6.3 ×(H) 2.1 mm (W) .173× (L) .248×(H) .083 inch approx. 25% of the volume and 50% of the footprint size of DIP type.



2. Low on-resistance (Typ. 26 Ω) for normally-closed type
This has been achieved thanks to the built-in MOSFET processed by our proprietary method, DSD (Double-Diffused and Selective Doping) method.

Cross section of the normally-closed type of power MOS



3. Controls low-level analog signals
PhotoMOS feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.

4. Low-level off state leakage current of max. 1 μA

TYPICAL APPLICATIONS

- Telephones
- Measuring instruments
- Computers
- Industrial robots
- High-speed inspection machines

TYPES

	Output rating*		Package	Part No.			Packing quantity	
	Load voltage	Load current		Tube packing style	Tape and reel packing style		Tube	Tape and reel
					Picked from the 1/2/3-pin side	Picked from the 4/5/6-pin side		
AC/DC dual use	400V	100mA	SOP6-pin	AQV414S	AQV414SX	AQV414SZ	1 tube contains: 75 pcs. 1 batch contains: 1,500 pcs.	1,000 pcs.

* Indicate the peak AC and DC values.
Note: For space reasons, only "V41S" is marked on the product. The two initial letters of the part number "AQ" and the packing style indicator "X" or "Z" have been omitted.

RATING

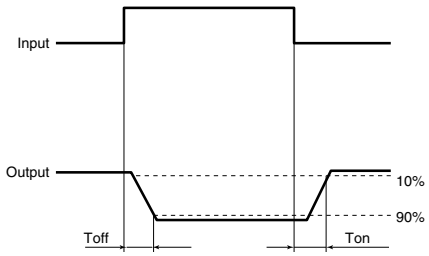
1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	Type of connection	AQV414S	Remarks
Input	LED forward current	I_F		50 mA	
	LED reverse voltage	V_R		5 V	
	Peak forward current	I_{FP}		1 A	f = 100 Hz, Duty factor = 0.1%
	Power dissipation	P_{in}		75 mW	
Output	Load voltage (peak AC)	V_L		400 V	
	Continuous load current	I_L	A	0.10 A	A connection: Peak AC, DC B, C connection: DC
			B	0.11 A	
			C	0.12 A	
	Peak load current	I_{peak}		0.3 A	A connection: 100 ms (1 shot) V_L= DC
	Power dissipation	P_{out}		450 mW	
Total power dissipation		P_T		500 mW	
I/O isolation voltage		V_{iso}		1,500 Vrms	
Ambient temperature	Operating	T_{opr}		–40 to +85°C –40 to +185°F	(Non-icing at low temperatures)
	Storage	T_{stg}		–40 to +100°C –40 to +212°F	

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item			Symbol	Type of connection	AQV414S	Condition
Input	LED operate (OFF) current	Typical	I_{Foff}	—	0.6 mA	I_L= Max.
		Maximum			3 mA	
	LED reverse (ON) current	Minimum	I_{Fon}	—	0.4 mA	I_L= Max.
		Typical			0.55 mA	
	LED dropout voltage	Typical	V_F	—	1.25 V (1.14 V at I_F = 5 mA)	I_F= 50 mA
		Maximum			1.5 V	
Output	On resistance	Typical	R_{on}	A	26 Ω	I_F= 0 mA I_L= Max. Within 1 s
		Maximum			50 Ω	
		Typical	R_{on}	B	20 Ω	I_F = 0 mA I_L = Max. Within 1 s
		Maximum			25 Ω	
		Typical	R_{on}	C	10 Ω	I_F = 0 mA I_L = Max. Within 1 s
		Maximum			12.5 Ω	
	Off state leakage current	Maximum	I_{Leak}	—	1 μA	I_F = 5 mA, V_L = Max.
Transfer characteristics	Operate (OFF) time*	Typical	T_{off}	—	0.47 ms	I_F= 0 mA → 5 mA V_L = Max.
		Maximum			1.0 ms	
	Reverse (ON) time*	Typical	T_{on}	—	0.28 ms	I_F= 5 mA → 0 mA V_L = Max.
		Maximum			1.0 ms	
	I/O capacitance	Typical	C_{iso}	—	0.8 pF	f = 1 MHz V_B = 0 V
		Maximum			1.5 pF	
	Initial I/C isolation resistance	Minimum	R_{iso}	—	1,000 MΩ	500 V DC

*Operate/Reverse time



3. Recommended operating conditions (Ambient temperature: 25°C 77°F)

Please use under recommended operating conditions to obtain expected characteristics.

Item		Symbol	Min.	Max.	Unit
LED current		I_F	5	30	mA
AQV414S	Load voltage (Peak AC)	V_L	—	320	V
	Continuous load current (A connection)	I_L	—	0.1	A

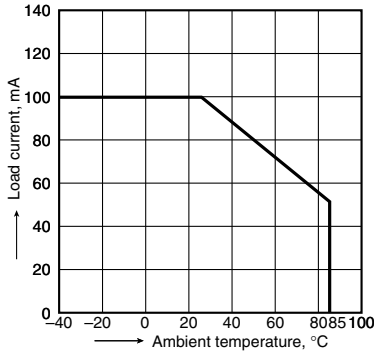
■ **These products are not designed for automotive use.**
If you are considering to use these products for automotive applications, please contact your local Panasonic Corporation technical representative.

REFERENCE DATA

1. Load current vs. ambient temperature characteristics

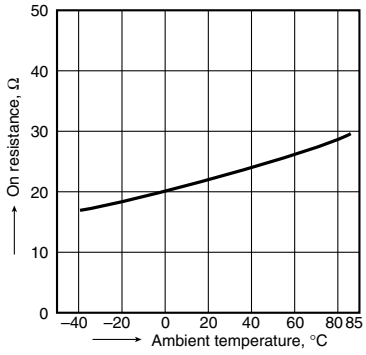
Allowable ambient temperature: –40 to +85°C
–40 to +185°F

Type of connection: A



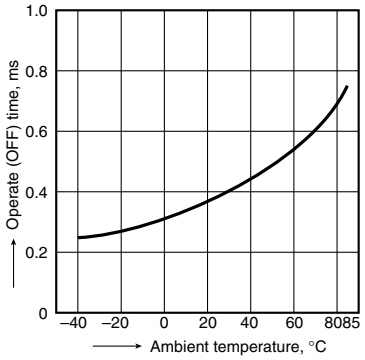
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 4 and 6;
LED current: 0 mA;
Continuous load current: 100 mA (DC)



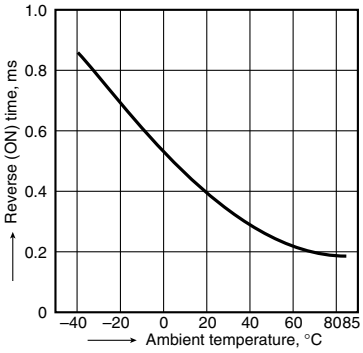
3. Operate (OFF) time vs. ambient temperature characteristics

LED current: 5 mA;
Load voltage: 400 V (DC);
Continuous load current: 100 mA (DC)



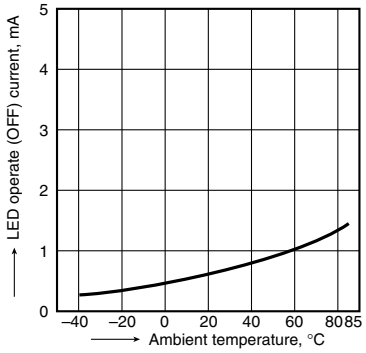
4. Reverse (ON) time vs. ambient temperature characteristics

LED current: 50 mA;
Load voltage: 400 V (DC);
Continuous load current: 100 mA (DC)



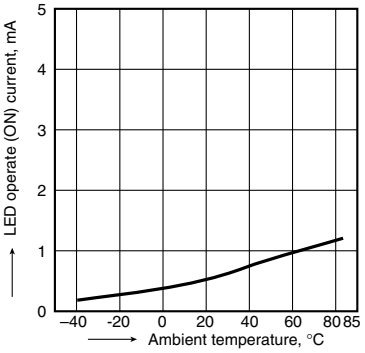
5. LED operate (OFF) current vs. ambient temperature characteristics

Load voltage: 400 V (DC);
Continuous load current: 100 mA (DC)



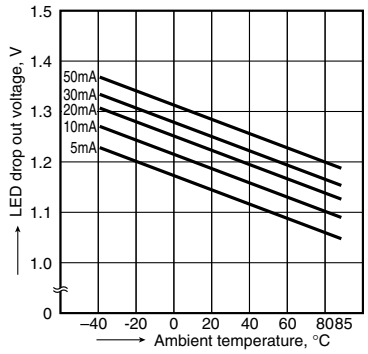
6. LED reverse (ON) current vs. ambient temperature characteristics

Load voltage: 400 V (DC);
Continuous load current: 100 mA (DC)



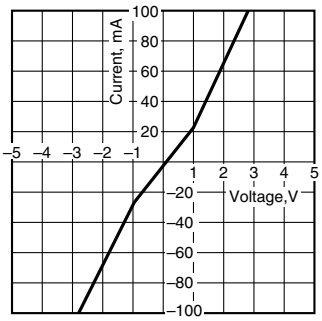
7. LED dropout voltage vs. ambient temperature characteristics

LED current: 5 to 50 mA



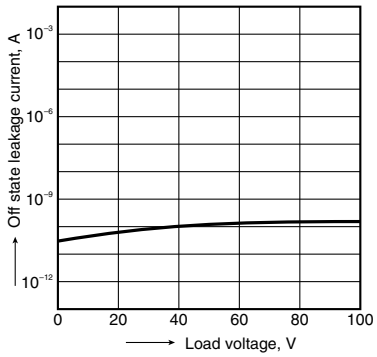
8. Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 4 and 6;
Ambient temperature: 25°C 77°F



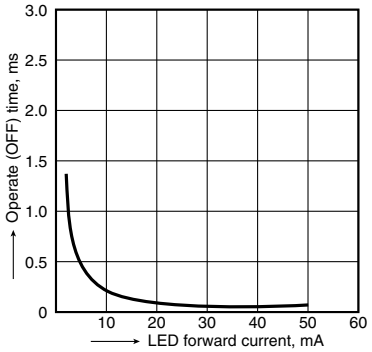
9. Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 4 and 6;
LED current: 5 mA;
Ambient temperature: 25°C 77°F



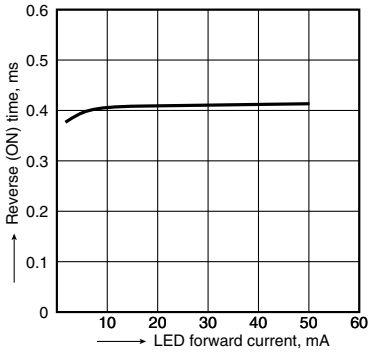
10. Operate (OFF) time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6;
Load voltage: 400 V (DC); Continuous load current: 100 mA (DC); Ambient temperature: 25°C 77°F



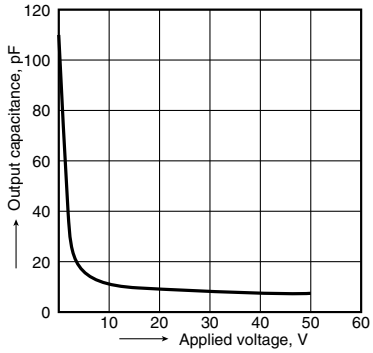
11. Reverse (ON) time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6;
Load voltage: 400 V (DC); Continuous load current: 100 mA (DC); Ambient temperature: 25°C 77°F



12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 4 and 6;
LED current: 5 mA; Frequency: 1 MHz;
Ambient temperature: 25°C 77°F



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